Small switching (30V, 0.1A)

2SK3541

Applications

Interfacing, switching (30V, 100mA)

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- Low voltage drive (2.5V) makes this device ideal for portable equipment.
- 4) Easily designed drive circuits.
- 5) Easy to parallel.

Structure

Silicon N-channel MOSFET

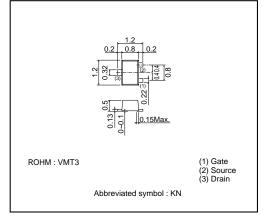
Absolute maximum ratings (Ta=25°C)

Paramet	Parameter		Limits	Unit
Drain-source voltage		VDSS	30	V
Gate-source voltage		Vgss	±20	V
	Continuous	lo	100	mA
Drain current	Pulsed	DP ^{*1}	400	mA
Reverse drain current	Continuous	Idr	100	mA
	Pulsed	DRP*1	400	mA
Total power dissipation	tion (Tc=25°C)	P D ^{*2}	150	mW
Channel temperatur	hannel temperature Tch		150	°C
Storage temperatur	e	Tstg	tg –55~+150 °C	

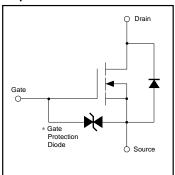
∗1 Pw≤10µs, Duty cycle<1%

*2 With each pin mounted on the recommended lands.

•External dimensions (Units : mm)



Equivalent circuit



*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use a protection circuit when the fixed voltages are exceeded.

Transistor

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	lgss	-	-	±1	μΑ	Vgs=±20V, Vds=0V
Drain-source breakdown voltage	V(BR)DSS	30	-	-	V	ID=10μA, Vgs=0V
Zero gate voltage drain current	IDSS	Ι	-	1.0	μΑ	VDS=30V, VGS=0V
Gate threshold voltage	VGS(th)	0.8	-	1.5	V	VDS=3V, ID=100µA
Static drain-source on-state	RDS(on)		5	8	Ω	ID=10mA, VGS=4V
resistance	RDS(on)	-	7	13	Ω	ID=1mA, VGs=2.5V
Forward transfer admittance	Y _{fs}	20	-	-	ms	ID=10mA, VDS=3V
Input capacitance	Ciss	-	13	-	pF	VDS=5V
Output capacitance	Coss	-	9	-	pF	Vgs=0V
Reverse transfer capacitance	Crss	-	4	-	pF	f=1MHz
Turn-on delay time	td(on)	-	15	-	ns	ID=10mA, VDD≒5V
Rise time	tr	-	35	-	ns	Vgs=5V
Turn-off delay time	td(off)	-	80	-	ns	RL=500Ω
Fall time	tr	I	80	-	ns	R _G s=10Ω

Packaging specifications

Туре	Package	Taping
	Code	T2R
	Basic ordering unit (pieces)	8000
2SK3541		0

•Electrical characteristic curves

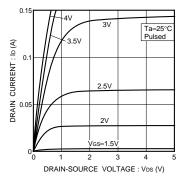


Fig.1 Typical output characteristics

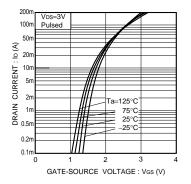


Fig.2 Typical transfer characteristics

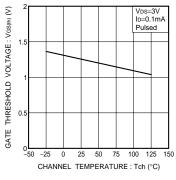
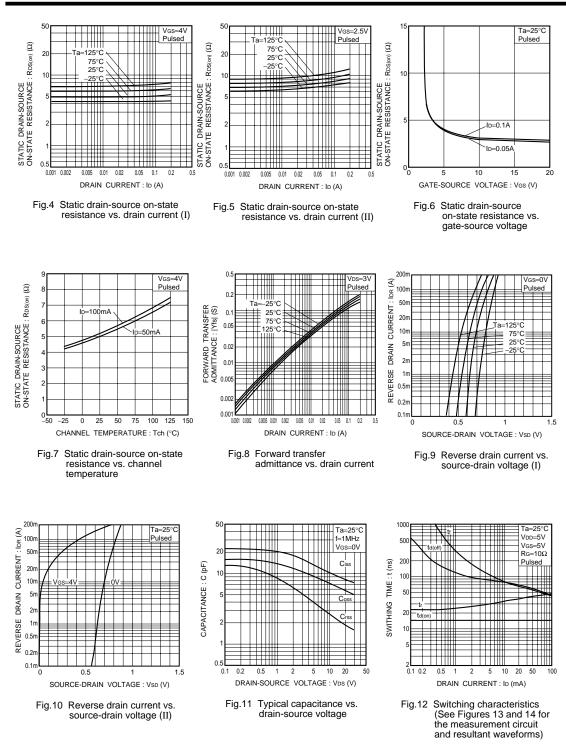


Fig.3 Gate threshold voltage vs. channel temperature

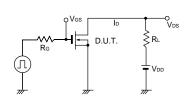
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Transistor



Transistor

•Switching characteristics measurement circuit



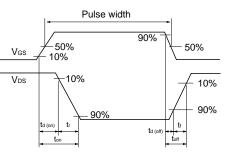


Fig.13 Switching time measurement circuit

Fig.14 Switching time waveforms

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